

3D PLUS

Memory Products Overview

28 April 2004 – ESTEC - Noordwijk
Technical presentations Day on
Microelectronic Packaging technologies

www.3d-plus.com

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3D PLUS Strategic Standard Products Lines

- **Memory Modules**
 - **SDRAM**
 - **DDR SDRAM**
 - **FLASH**
 - **SRAM**
 - **DPRAM**
 - **EEPROM**
 - **Mixed Modules (SRAM + EEPROM)**
- **Computer Modules**
 - **DSP ATMEL TSC21020F**
 - **DSP Texas Instruments C6000 and C5500**
- **Camera Head and Sensors Modules**
- **DC/DC Converters Modules**
 - **4W**
 - **10W (in development)**



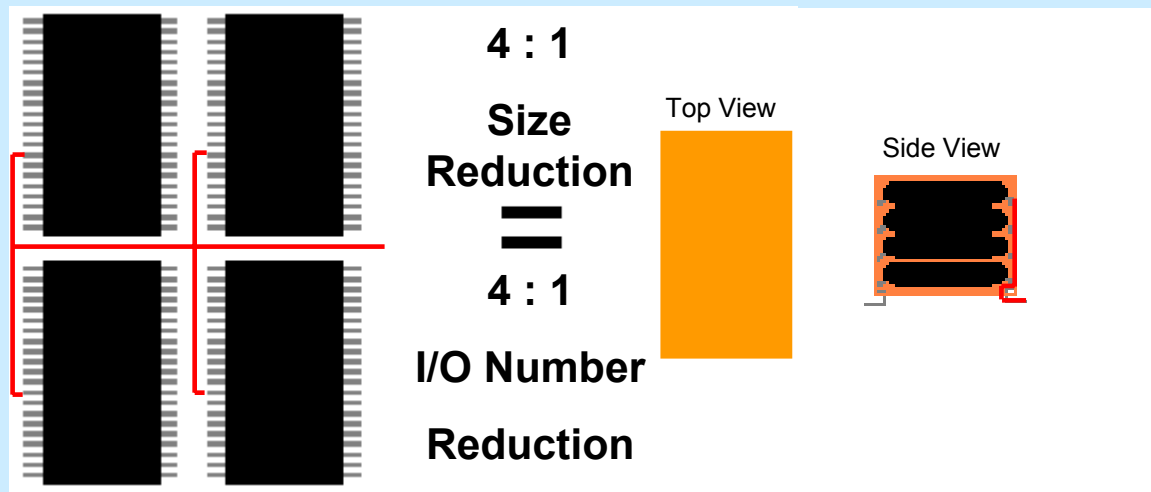
3D PLUS Memory Modules Benefits Overview

- **Miniaturization (Save up to 80 % Space in the design),**
- **Very High Density,**
- **Wide Bit Organization (x 32, x 48, x 64, x 72, ... and more if needed),**
- **High Operating Speed,**
- **High Signal Integrity and Immunity to Noise and Ground Bounce,**
- **Low-Power Consumption,**
- **High Reliability – MTBF**
- **Space quality level Manufacturing & screening flow**
- **Characterization in terms of radiations tolerance (TID & SEE)**

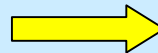


3D PLUS Concept & Technology for Memory Modules

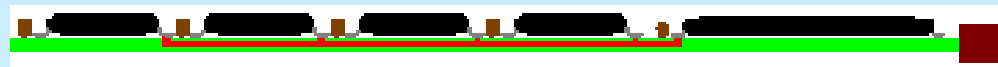
A Technology for More Memory Performance in Smaller Spaces :



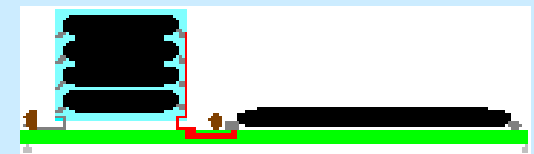
Four Memory Packages
(Die, CSP, TSOP, CSP, μ BGA, ...)



One 3D Memory Module



System board

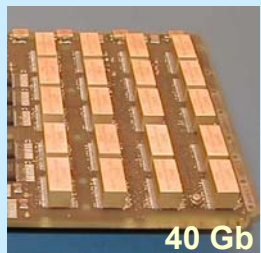
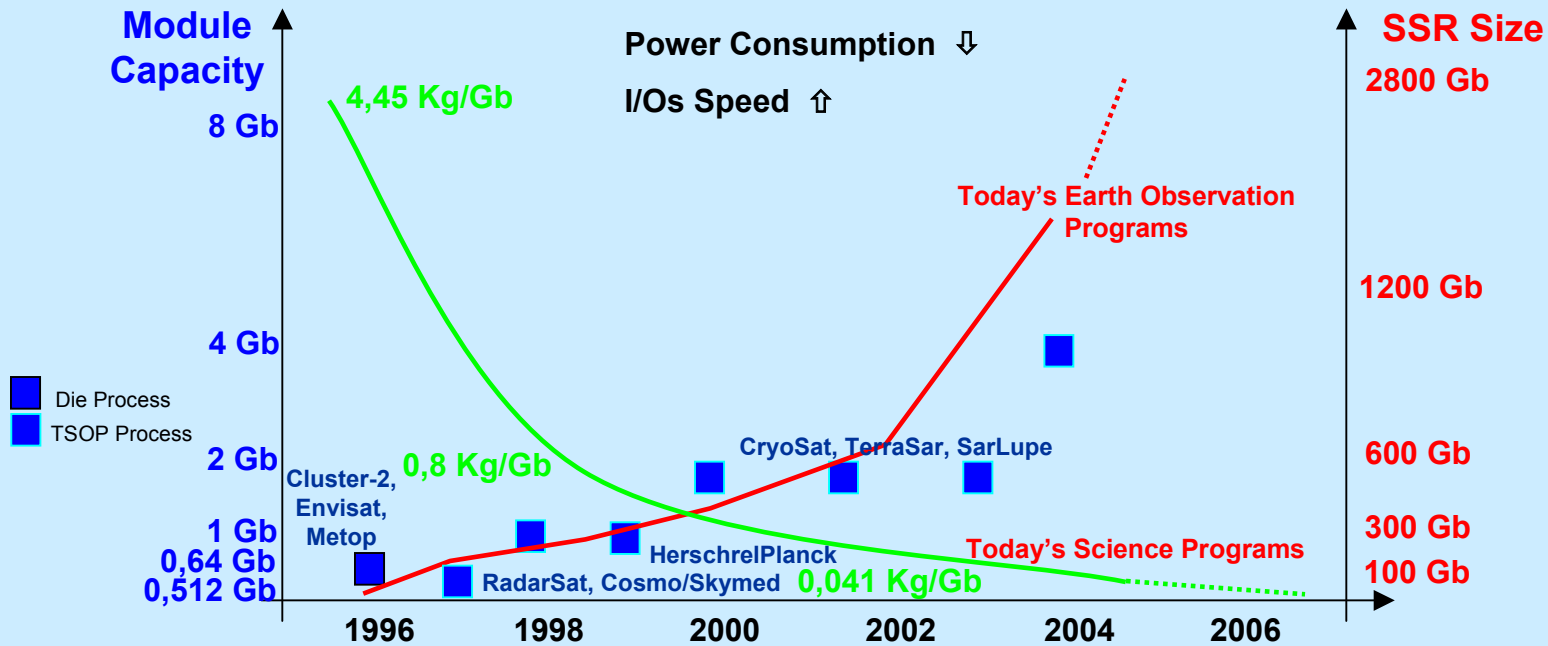


System board
embedding 3-D module

75 % Electrical Length and Parasitic elements Reduction



3D PLUS Heritage for Solid State Recorders

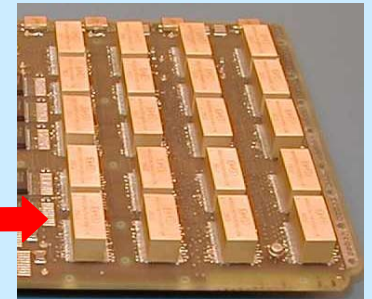


3D PLUS Memory Modules Highlights

Memory Solutions for Computer Boards, « Disc On Chip » and Mass Data Storage :



- 2 Gb to 8 Gb SDRAM Memory Modules

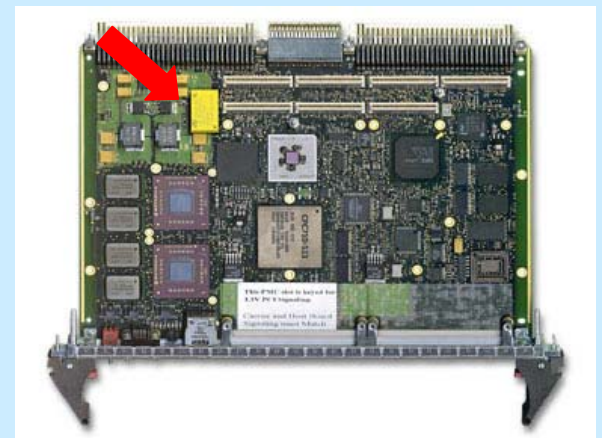


- 1 Gb to 2 Gb DDR SDRAM Memory Modules

- 8 Gb to 16 Gb FLASH Memory Modules

- 16 Mb to 64 Mb SRAM Memory Module

- 4 Mb to 8 Mb EEPROM Memory Modules

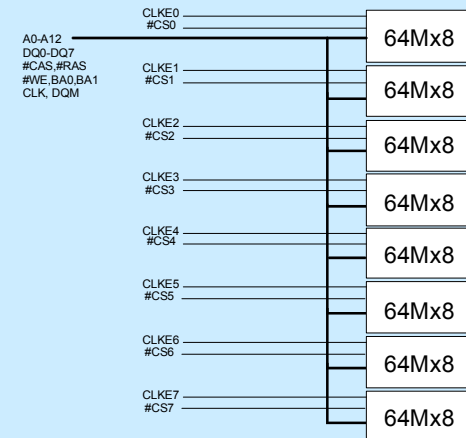


4 Gb SDRAM Memory Module

- Description :
Stack of eight 512 Mb SDRAM
- Part Number:
MMSD08512808S-E or MMSD04102408S-E
- Memory Organization :
512M x 8 or 1G x 4 (other memory organization possible)
- Packaging :
SOP 58-08 or SOP 54-08 (24 * 11 * 12 mm)
- Features :
Targeted for Data Storage Systems
Independent CS and CLKE for each SDRAM Die
⇒ Total Power Consumption Management possibility
- Basic Memory cell :
512 Mb DDP or Single Chip
- SDRAM Product Life Cycle Management under control of 3D PLUS
- Other New Products : 2 Gb SDRAM Memory Module (stack of four TSOPs on plusD)



Block Diagram



8 Gb FLASH Memory Module

- Description :

Stack of eight 1 Gb FLASH

- Part Number:

MMFN08102808S-F

- Memory Organization :

1G x 8 (other memory organization possible)

- Packaging :

SOP 50-05 or SOP 54-08 (18,7 * 13,5 * 12 mm)

- Features :

Targeted for Mass Data Storage Application

Independant control of each FLASH Memory integrated in the Module for High speed Access

- Basic Memory cell :

1 Gb from SAMSUNG

Other Memory Supplier can be used (TOSHIBA, AMD, ...)

- FLASH Product Life Cycle Management under control of 3D PLUS

- Other New Products : 4 Gb FLASH Memory Module (stack of four TSOPs only)



16 Mb SRAM Memory Module

- Description :

Stack of four 4 Mb SRAM or sixteen 1Mb SRAM

- Part Number:

MMSR32510604S-

MMSR16001808S-CR (Cooperation with ATMEL – PN: AT61162E)

- Memory Organization :

512k x 32, 1Mx16, 2Mx8

- Packaging :

SOP 64-08 (28 * 11 * H)

- Features : cf. block diagram for x32 organisation

- Basic Memory cell :

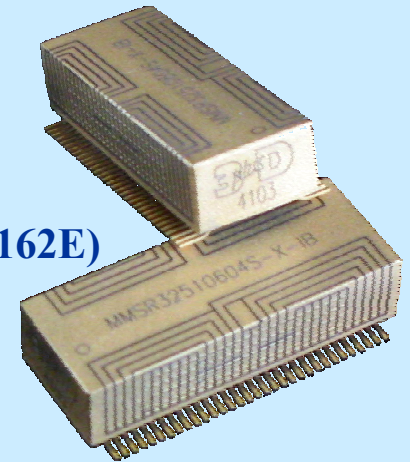
4 Mb SAMSUNG Rev. C, (TSOP)

1 Mb ATMEL 65609E, QML-Q (Die)

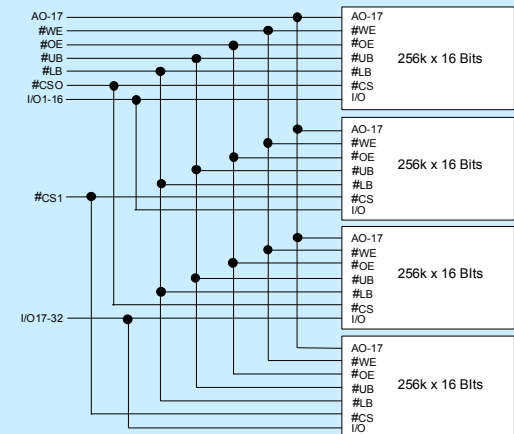
⇒Good behavior in the temperature range

⇒Good radiation tolerance performance

- Other Products : 32 Mb SRAM Memory Module (stack of eight TSOPs)



BLOCK DIAGRAM



4 Mb EEPROM Memory Module

•Description :
Stack of four 1 Mb EEPROM

•Part Number:
MMEE08510804SCC

•Memory Organization :
512K x 8 (x32 memory organization possible)

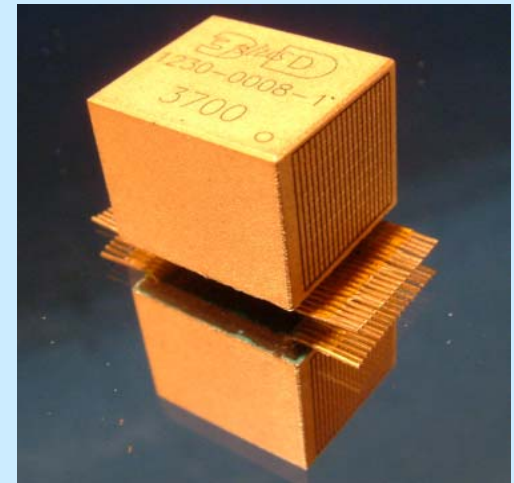
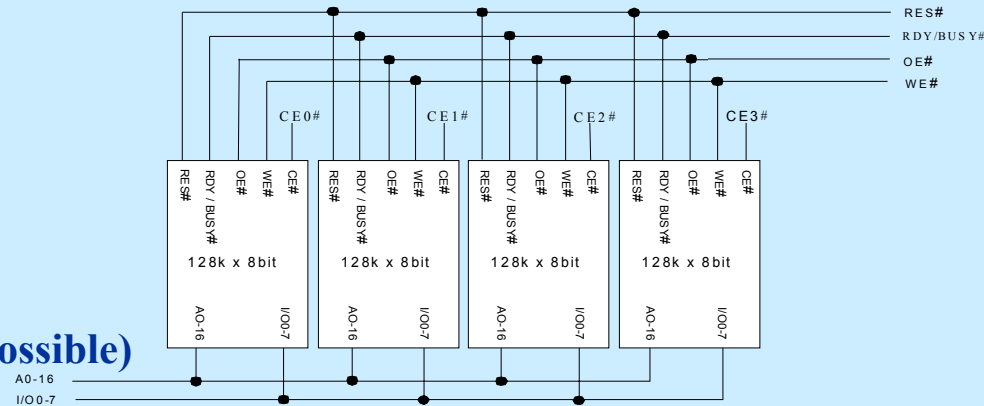
•Packaging :
SOP 40-05 – Package G4 (13,2 * 11,7 * 7,5 mm)
⇒75 % Area Savings
⇒80 % weight Savings against other solutions

•Features : cf. block diagram

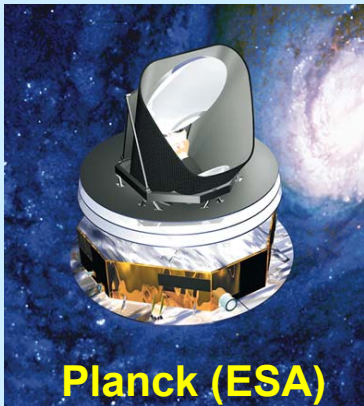
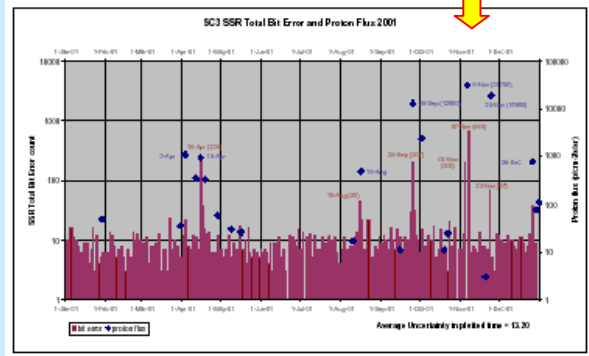
•Basic Memory cell :
1 Mb EEPROM (128k x 8) ref. HN58C1001T-15 (TSOP)
⇒Good behavior in the temperature range
⇒Good radiation tolerance performance

•EEPROM Product Life Cycle Management under control of 3D PLUS

•Other New Products : 8 Mb EEPROM Memory Module (stack of eight TSOPs only)



3D PLUS Flight Proven Technology and Products



3D PLUS Product Highlights for 2004

These Products are a short list of the 3D PLUS product range available on our Web Site :

www.3d-plus.com

Don't hesitate to contact us to discuss your needs...in the 3rd Dimension

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